

CR6CM-12A

Thyristor

Medium Power Use

REJ03G1706-0100 Rev.1.00 Jul 03, 2008

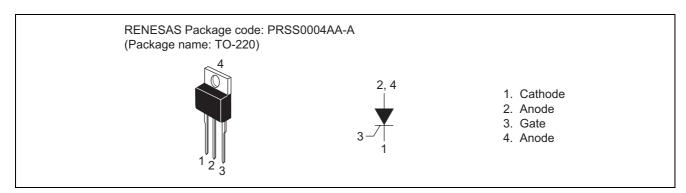
Features

 $\begin{array}{ll} \bullet & I_{T\,(AV)}: 6\;A \\ \bullet & V_{DRM}: 600\;V \\ \bullet & I_{GT}: 10\;mA \end{array}$

Non-Insulated Type

Planar Passivation Type

Outline



Applications

Switching mode power supply, regulator for autocycle, motor control, heater control, and other general purpose control applications

Maximum Ratings

Parameter	Symbol	Voltage class	Unit
raidilletei	Symbol	12	
Repetitive peak reverse voltage	V_{RRM}	600	V
Non-repetitive peak reverse voltage	V _{RSM}	720	V
DC reverse voltage	V _{R (DC)}	480	V
Repetitive peak off-state voltage	V_{DRM}	600	V
DC off-state voltage	V _{D (DC)}	480	V

Parameter	Symbol	Ratings	Unit	Conditions
RMS on-state current	I _{T (RMS)}	9.4	Α	
Average on-state current	I _{T (AV)}	6	А	Commercial frequency, sine half wave 180° conduction, Tc = 96°C ^{Note1}
Surge on-state current	I _{TSM}	90	А	50Hz sine half wave 1 full cycle, peak value, non-repetitive
I ² t for fusing	l ² t	41	A ² s	Value corresponding to 1 cycle of half wave 50Hz, surge on-state current
Peak gate power dissipation	P _{GM}	5	W	
Average gate power dissipation	P _{G (AV)}	0.5	W	
Peak gate forward voltage	V_{FGM}	6	V	
Peak gate reverse voltage	V_{RGM}	10	V	
Peak gate forward current	I _{FGM}	2	Α	
Junction temperature	Tj	- 40 to +125	°C	
Storage temperature	Tstg	- 40 to +125	°C	
Mass	_	2.0	g	Typical value

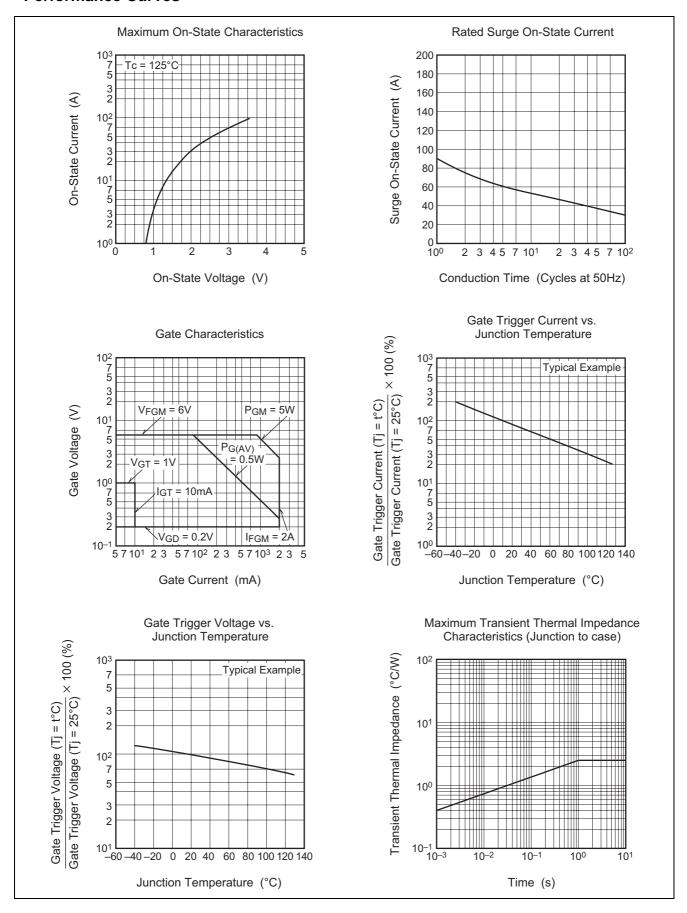
Electrical Characteristics

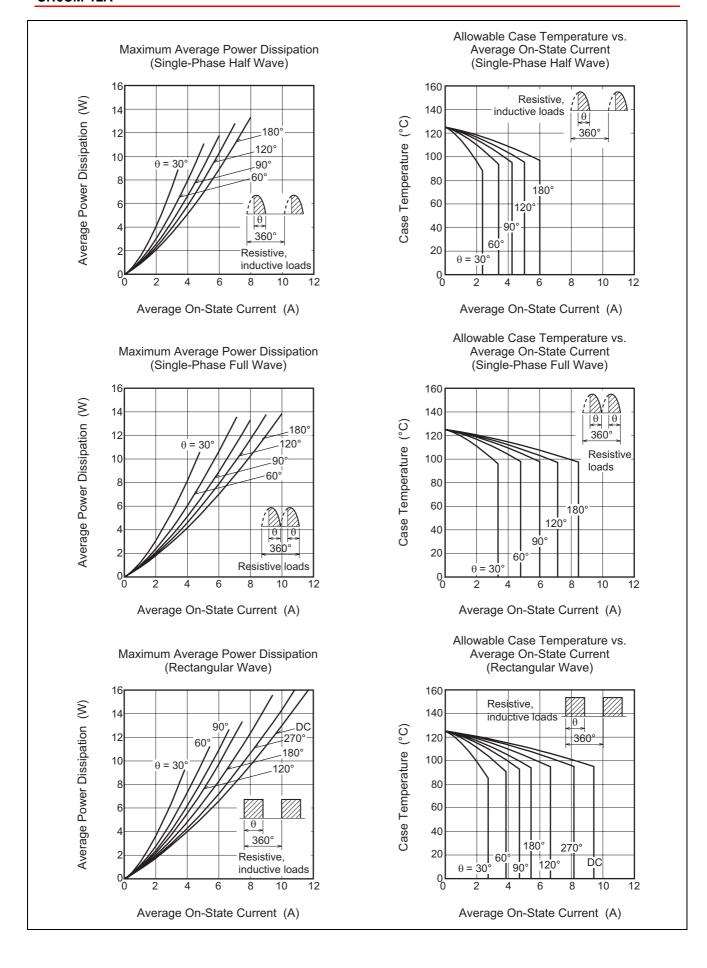
Parameter	Symbol	Min.	Тур.	Max.	Unit	Test conditions
Repetitive peak reverse current	I _{RRM}	_	_	2.0	mA	Tj = 125°C, V _{RRM} applied
Repetitive peak off-state current	I _{DRM}	_	_	2.0	mA	Tj = 125°C, V _{DRM} applied
On-state voltage	V _{TM}	_	_	1.7	V	Tc = 25°C, I _{TM} = 20 A,
						instantaneous value
Gate trigger voltage	V_{GT}	_	_	1.0	V	$Tj = 25$ °C, $V_D = 6$ V, $I_T = 1$ A
Gate non-trigger voltage	V_{GD}	0.2	_	_	V	$Tj = 125$ °C, $V_D = 1/2 V_{DRM}$
Gate trigger current	I _{GT}	_	_	10	mA	$Tj = 25$ °C, $V_D = 6$ V, $I_T = 1$ A
Holding current	I _H	_	15	_	mA	Tj = 25°C, V _D = 12 V
Thermal resistance	R _{th (j-c)}	_	_	2.5	°C/W	Junction to case ^{Note1 Note2}

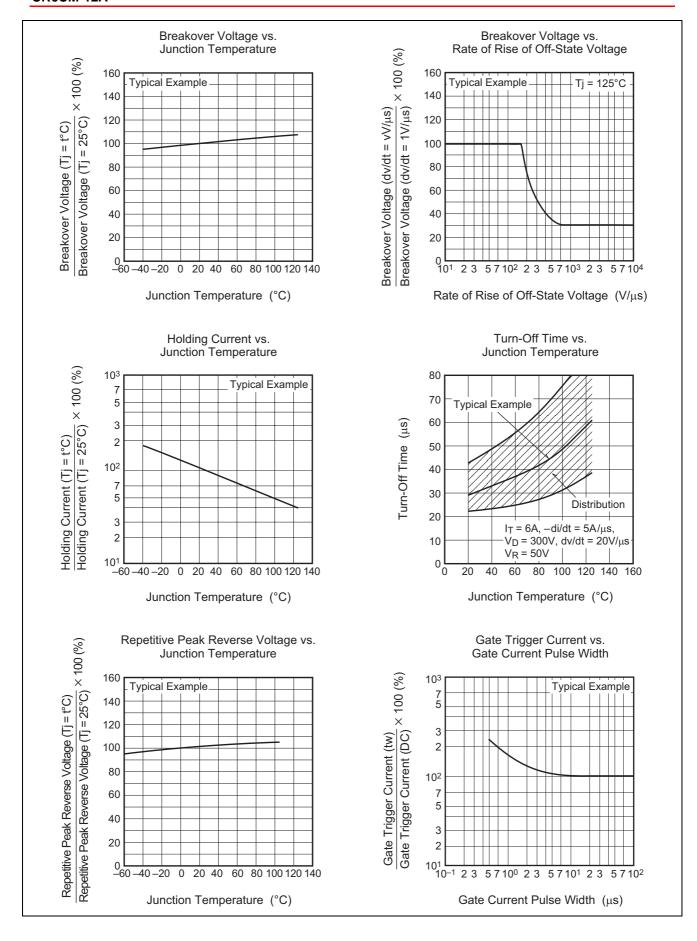
Notes: 1. Case temperature is measured at anode tab 1.5 mm away from the molded case.

^{2.} The contact thermal resistance $R_{th\,(c\text{-}f)}$ in case of greasing is 1.0°C/W.

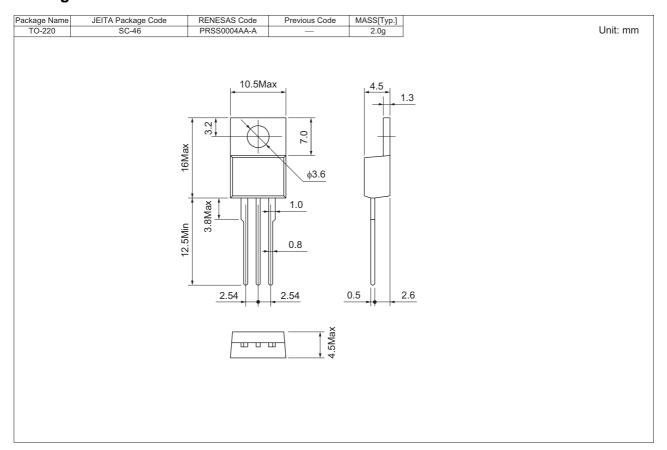
Performance Curves







Package Dimensions



Order Code

Lead form	Standard packing	Quantity	Standard order code	Standard order code example
Straight type	Vinyl sack	100	Type name	CR6CM-12A
Lead form	Plastic Magazine (Tube)	50	Type name – Lead forming code	CR6CM-12A-A8

Note: Please confirm the specification about the shipping in detail.

Renesas Technology Corp. sales Strategic Planning Div. Nippon Bldg., 2-6-2, Ohte-machi, Chiyoda-ku, Tokyo 100-0004, Japan

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Renesas Technology America, Inc.

450 Holger Way, San Jose, CA 95134-1368, U.S.A Tel: <1> (408) 382-7500, Fax: <1> (408) 382-7501

Renesas Technology Europe Limited
Dukes Meadow, Millboard Road, Bourne End, Buckinghamshire, SL8 5FH, U.K.
Tel: <44> (1628) 585-100, Fax: <44> (1628) 585-900

Renesas Technology (Shanghai) Co., Ltd.
Unit 204, 205, AZIACenter, No.1233 Lujiazui Ring Rd, Pudong District, Shanghai, China 200120 Tel: <86> (21) 5877-1818, Fax: <86> (21) 6887-7858/7898

Renesas Technology Hong Kong Ltd.
7th Floor, North Tower, World Finance Centre, Harbour City, Canton Road, Tsimshatsui, Kowloon, Hong Kong Tel: <852> 2265-6688, Fax: <852> 2377-3473

Renesas Technology Taiwan Co., Ltd. 10th Floor, No.99, Fushing North Road, Taipei, Taiwan Tel: <886> (2) 2715-2888, Fax: <886> (2) 3518-3399

Renesas Technology Singapore Pte. Ltd.
1 Harbour Front Avenue, #06-10, Keppel Bay Tower, Singapore 098632 Tel: <65> 6213-0200, Fax: <65> 6278-8001

Renesas Technology Korea Co., Ltd. Kukje Center Bldg. 18th Fl., 191, 2-ka, Hangang-ro, Yongsan-ku, Seoul 140-702, Korea Tel: <82> (2) 796-3115, Fax: <82> (2) 796-2145

Renesas Technology Malaysia Sdn. Bhd
Unit 906, Block B, Menara Amcorp, Amcorp Trade Centre, No.18, Jln Persiaran Barat, 46050 Petaling Jaya, Selangor Darul Ehsan, Malaysia Tel: <603> 7955-9390, Fax: <603> 7955-9510